



LOW LEVEL AMPS

Type No.	Case Style	V _{CE0} (V) Min	V _{BE0} (V) Min	I _{CE0} (mA) Max	V _{CE0} (V) Max	h _{FE} Min	I _C @ (mA)	V _{CE(SAT)} (V) Max	V _{BE(SAT)} (V) Min	I _C (mA) Max	C _{ob} (pF) Max	f _T (MHz) Min	I _C (mA) Max	NF (dB) Max	Test Conditions	Process No.
2N760	TO-18	45	8	200	30	76	300	1.0	0.6	1.1	8	50	1.0			07
2N760A	TO-18	60	8	100	30	76	333	1.0	1.1	10	8	50	1.0			07
2N929	TO-18	45	5	10	45	60	350	1.0	0.6	1.0	8	30	0.5	4	1	07
2N929A	TO-18	60	6	2	45	40	350	0.5	0.7	0.9	6	45	0.5	4		07
2N930	TO-18	45	5	10	45	150	600	1.0	0.6	1.0	8	30	0.5	3	1	07
2N2484	TO-18	60	6	10	45	200	500	0.35		1	10	15	0.05	3	1	07
2N2509	TO-18	125	7	5	100	40	10	1.0	0.9	5	6	45	5	7	1	07
2N2510	TO-18	100	7	5	80	150	500	1.0	0.9	5	6	45	5	4	2	07
2N2511	TO-18	80	7	5	60	240	750	1.0	0.9	5	6	45	5	4	2	07
2N2586	TO-18	60	6	2	45	150	600	0.5	0.7	0.9	7	45	0.5	3.5	2	07
2N3117	TO-18	60	6	10	45	400	1	0.35		1	4.5	60	0.5	1	2	0729-01
2N3246	TO-18	60	10	1	40	400	800	0.5	0.7	0.9	5	60	180	1	1	0701



LOW LEVEL AMPS (Continued)

TEST CONDITIONS:

(1) $I_C = 10 \mu A$, $V_{CE} = 5V$, $f = 10 \text{ Hz}$ -15.7 kHz. (2) $I_C = 10 \mu A$, $V_{CE} = 5V$, $f = 1 \text{ kHz}$. (3) $I_C = 5 \mu A$, $V_{CE} = 5V$, $f = 1 \text{ kHz}$. (4) $I_C = 100 \mu A$, $V_{CE} = 5V$, $f = 10 \text{ Hz}$ -15.7 kHz. (5) $I_C = 10 \mu A$, $V_{CE} = 5V$, $f = 10 \text{ kHz}$. (6) $I_C = 100 \mu A$, $V_{CE} = 5V$, $f = 5 \text{ kHz}$.

JFET Transistors



LOW LEVEL AMPS (Continued)

Type No.	Case Style	V _{CE} (V) Min	V _{CE} (V) Min	V _{BE} (V) Min	I _{CEO} (nA) Max	V _{CB} (V) Min	h _{FE} Min	I _C (mA) Max	V _{CE} (V) Min	V _{CE(SAT)} (V) Max	V _{BE(SAT)} (V) Min	I _C (mA) Max	C _{ob} (pF) Max	f _T (MHz) Min	I _C (mA) Max	NF (dB) Max	Test Conditions	Process No.
2N4410	TO-92 (92)	120	80	5	10	100	60	400	1	0.2	0.8	1	12	60	300	10		07
2N4966	TO-92 (92)	50	40	6	25	25	40	200	0.01	0.4		10	6	40	1			07
2N4967	TO-92 (92)	50	40	6	25	25	100	600	0.01	0.4		10	6	40	1			07
2N4968	TO-92 (92)	30	25	6	50	25	40	200	0.01	0.4		10	6					07
2N5088	TO-92 (92)	35	30		50	20	300	10	5	0.5		10	4			3	3	07
2N5089	TO-92 (92)	30	25		50	15	400	100	5	0.5		10	4			2	3	07
2N5133	TO-92 (92)	20	18	3	50	15	60	1000	1 mA	0.4		1	5					07
2N5209	TO-92 (92)	50	50		50	35	150	10	5	0.7		10	4	30	0.5	4	5	07
2N5210	TO-92 (92)	50	50		50	35	250	10	5	0.7		10	4	30	0.5	3	4	07
2N5232	TO-92 (94)		50		30	50	200	600	100 μA	0.125		10	4					07
2N5232A	TO-92 (94)		50		30	50	250	500	2	0.125		10	4					07
MPS3707	TO-92 (92)		30		100	20	100	400	100 μA	1.0		10				5	4	07
MPS3708	TO-92 (92)		30		100	20	45	660	1	1.0		10						07
MPS3709	TO-92 (92)		30		100	20	45	165	1	1.0		10						07
MPS3710	TO-92 (92)		30		100	20	90	330	1	1.0		10						07
MPS3711	TO-92 (92)		30		100	20	180	660	1	1.0		10						07
MPS6571	TO-92 (92)	25	20	3	50	20	250	1000	100 μA	0.5		10	4.5	50	0.5			07
MPSA09	TO-92 (92)	50	50		100	25	100	600	100 μA	0.9		10	5	600	0.5			07

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LOW LEVEL AMPS (Continued)

Type No.	Case Style	V _{CB0} (V) Min	V _{CE0} (V) Min	V _{EB0} (V) Min	I _{CB0} (nA) Max	h _{FE} @ Min Max	I _C & (mA)	V _{CE} (V) Max	V _{CE} (SAT) (V) Max	V _{BE} (SAT) (V) Min Max	I _C (mA) Max	C _{ob} (pF) Max	f _T (MHz) Min Max	I _C (mA) Max	NF (dB) Max	Test Conditions	Process No.
PE4010	TO-92 (92)	30	25	6	200	5	1000	1	0.35	0.5	1	4	20 60	0.05 1			07
PN930	TO-92 (92)	45	45	5	10	45	600 150 100	10 500 μ A 10 μ A	5	1.0	1.0	10	8	30	0.5	3	07
PN2484	TO-92 (92)	60	60	6	10	45	800 250 200 175 100 30	10 1 500 μ A 100 μ A 10 μ A 1 μ A	5	0.35	10	6					07
PN3565	TO-92 (92)	30	25	6	50	25	600	1	0.35		1	4	40	240	1		07
PN5133	TO-92 (92)	20	18	3	50	15	1000	1	0.4		1	5	40	240	1		07

TEST CONDITIONS:

(1) I_C = 10 μ A, V_{CE} = 5V, f = 10 Hz-15.7 kHz. (2) I_C = 10 μ A, V_{CE} = 5V, f = 1 kHz. (3) I_C = 5 μ A, V_{CE} = 5V, f = 1 kHz. (4) I_C = 100 μ A, V_{CE} = 5V, f = 10 Hz-15.7 kHz. (5) I_C = 10 μ A, V_{CE} = 5V, f = 10 kHz. (6) I_C = 100 μ A, V_{CE} = 5V, f = 5 kHz.

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GENERAL PURPOSE AMPS AND SWITCHES

Type No.	Case Style	V _{CB0} (V) Min	V _{CE0} (V) Min	V _{EB0} (V) Min	I _{CB0} (nA) Max	h _{FE} @ Min Max	I _C & (mA)	V _{CE} (V) Max	V _{CE} (SAT) (V) Max	V _{BE} (SAT) (V) Min Max	I _C (mA) Max	C _{ob} (pF) Max	f _T (MHz) Min Max	I _C (mA) Max	t _{off} (ns) Max	NF (dB) Max	Test Conditions	Process No.
MPS3903	TO-92 (92)	60	40	6			0.1 1 150 50 100	1 1 1 1 1	0.2	0.65	0.85	10	4	200	10	5	8	02

TEST CONDITIONS:

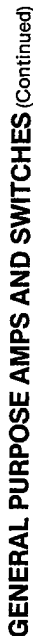
(1) I_C = 300 μ A, V_{CE} = 10V, f = 1 kHz. (2) I_C = 150 mA, V_{CE} = 30V, I_B¹ = I_B² = 15 mA. (3) I_C = 100 μ A, V_{CE} = 10V, f = 1 kHz. (4) I_C = 300 mA, V_{CE} = 25V, I_B¹ = I_B² = 30 mA. (5) I_C = 100 μ A, V_{CE} = 4.5V, f = 15.7 kHz. (6) I_C = 10 mA, V_{CE} = 3V, I_B¹ = I_B² = 1 mA. (7) I_C = 100 μ A, V_{CE} = 5V, f = 15.7 kHz. (8) I_C = 250 μ A, V_{CE} = 5V, f = 10 Hz-15.7 kHz. (9) I_C = 3 mA, V_{CE} = 10V, f = 1 MHz. (10) I_C = 10 μ A, V_{CE} = 5V, f = 15.7 kHz.



GENERAL PURPOSE AMPS AND SWITCHES (Continued)

Type No.	Case Style	V _{CE0} (V) Min	V _{CE0} (V) Min	V _{BE0} (V) Min	I _{CBO} (nA) Max	V _{CB} (V)	h _{FE} Min	h _{FE} Max	I _C @ (mA)	V _{CE} (V)	V _{CE(SAT)} (V) Max	V _{BE(SAT)} (V) Min	V _{BE(SAT)} (V) Max	I _C @ (mA) Max	C _{ob} (pF) Max	f _T (MHz) Min	f _T (MHz) Max	I _C (mA) Max	t _{off} (ns) Max	NF (dB) Max	Test Conditions	Process No.
MPS3904	TO-92 (92)	60	40	6			40	70	100	0.1	1	0.2	0.65	0.85	10	4	200	10		5	8	02
MPS6573	TO-92 (92)		35		100	35	100	200	500	10	5	0.5			10	12	100	300	10			02
MPS6574	TO-92 (92)		35		100	35	100	200	300	1	5	0.5			10	12	100	300	10			02
MPS6575	TO-92 (92)		45		100	45	100	200	500	10	5	0.5			10	12	100	300	10			02
MPS6576	TO-92 (92)		45		100	45	100	200	300	1	5	0.5			10	12	100	300	10			02
MPSA20	TO-92 (92)		40	4	100	30	40	400	5	10						4	125	5				02
2N2923	TO-92 (94)	25	25	5	100	25	90	180	2	10						10						04
2N2924	TO-92 (94)	25	25	5	100	25	150	300	2	10						10						04
2N2925	TO-92 (94)	25	25	5	100	25	235	470	2	10						10						04
2N2926	TO-92 (94)	18	18	5	500	18	35	470	2	10						10						04
2N3390	TO-92 (94)	25	25	5	100	18	400	800	2	4.5						10						04
2N3391	TO-92 (94)	25	25	5	100	18	250	500	2	4.5						10				5	5	04
2N3391A	TO-92 (94)	25	25	5	100	18	250	500	2	4.5						10				5	5	04
2N3392	TO-92 (94)	25	25	5	100	18	150	300	2	4.5						10						04
2N3393	TO-92 (94)	25	25	5	100	18	90	180	2	4.5						10						04
2N3395	TO-92 (94)	25	25	5	100	18	150	500	2	4.5						10						04
2N3396	TO-92 (94)	25	25	5	100	18	90	500	2	4.5						10						04
2N3397	TO-92 (94)	25	25	5	100	18	55	500	2	4.5						10						04

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(1) $I_C = 300 \mu A$, $V_{CE} = 10V$, $f = 1$ kHz. (2) $I_C = 150$ mA, $V_{CC} = 30V$, $I_B^1 = I_B^2 = 15$ mA. (3) $I_C = 100 \mu A$, $V_{CE} = 10V$, $f = 1$ kHz. (4) $I_C = 300$ mA, $V_{CC} = 25V$, $I_B^1 = I_B^2 = 30$ mA. (5) $I_C = 100 \mu A$, $V_{CE} = 4.5V$, $f = 15.7$ kHz. (6) $I_C = 10$ mA, $V_{CC} = 3V$, $I_B^1 = I_B^2 = 1$ mA. (7) $I_C = 100 \mu A$, $V_{CE} = 5V$, $f = 15.7$ kHz. (8) $I_C = 250 \mu A$, $V_{CE} = 5V$, $f = 10$ Hz-15.7 kHz. (9) $I_C = 3$ mA, $V_{CE} = 10V$, $f = 1$ MHz. (10) $I_C = 10 \mu A$, $V_{CE} = 5V$, $f = 15.7$ kHz.



GENERAL PURPOSE AMPS AND SWITCHES (Continued)

Type No.	Case Style	V _{CE0} (V) Min	V _{BE0} (V) Min	I _{CB0} (mA) Max	V _{CB} (V)	h _{FE} e _{IC} & V _{CE} (V)	V _{CE} (SAT) V _{BE} (SAT) & (V) Min Max	I _C (mA) e _{IC} (mA) Max	C _{ob} (pF) Max	f _T (MHz) Min Max	I _C (mA) e _{IC} (mA) Max	t _{off} (ns) Max	NF (dB) Max	Test Conditions	Process No.
2N3704	TO-92 (94)	50	30	5	100	20	2	100 300 50	0.6	100	100	12			13
2N3705	TO-92 (94)	50	30	5	100	20	2	50 150 50	0.8	100	100	12			13
2N3706	TO-92 (94)	40	20	5	100	20	2	30 600 50	1.0	100	100	12			13
2N3794	TO-92 (94)	40	20	5	500	15	10	100 100 100 600 10 10 35 1	0.4	100 600 10	10	10	100 600 10		13
2N4400	TO-92 (92)	60	40	6			2	20 500 150 150 10 40 10 1 20 1	0.4 0.75 0.95 1.2	200	20	255		2	13
2N4401	TO-92 (92)	60	40	6			1	40 500 150 150 10 80 10 1 40 1 20 100 μA 1	0.4 0.75 0.95 1.2	250	20	255		2	13
2N4944	TO-92 (92)	80	40	5	50	40	1	40 120 150 150 30 40	0.25	60 900	50				13
2N4946	TO-92 (92)	80	40	5	50	40	1	100 300 150 150 30 100	0.25	60 900	50				13
2N4951	TO-92 (94)	60	30	5	50	40	10	60 200 150 150 10 40 10 10 20 1	0.3 1.3	250	20	400	2		13
2N4952	TO-92 (94)	60	30	5	50	40	10	100 300 150 150 10 75 10 10 50 1	0.3 1.3	250	20	400	2		13
2N4953	TO-92 (94)	60	30	5	50	40	10	200 600 150 150 10 150 10 10 75 1	0.3 1.3	250	20	400	2		13
2N4954	TO-92 (94)	40	30	5	50	30	10	60 600 150 150 10 40 10 10 20 1	0.3 1.3	250	20	400	2		13
2N5220	TO-92 (92)	15	15	3	100	10	10	30 600 50 10 25 10	0.5 1.1	100	20				13
2N5225	TO-92 (92)	25	25	4	300	15	10	30 600 50 10 25 50	0.8 1.0	50	20				13
2NPS3704	TO-92 (92)	50	30	5	100	20	2	100 300 50	0.6	100	100	12			13

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GENERAL PURPOSE AMPS AND SWITCHES (Continued)

Type No.	Case Style	V _{CEO} (V) Min	V _{CE0} (V) Min	V _{EB0} (V) Min	ICB0 (mA) Max	ICB0 @ V _{CB} (V)	hFE Min	hFE Max	IC @ VCE (V)	VCE(SAT) (V) Max	VBE(SAT) (V) Min	IC @ VBE(SAT) (mA) Max	Cob (pF) Max	f _T (MHz) Min	f _T @ IC (mA) Max	t _{off} (ns) Max	NF (dB) Max	Test Conditions	Process No.
MPS3705	TO-92 (92)	50	30	5	100	20	50	150	50	2	0.8	100	12	100	50				13
MPS3706	TO-92 (92)	40	20	5	100	20	30	600	50	2	1.0	100	12	100	50				13
MPS6522	TO-92 (92)		25	4	50	20	100	400	0.1	10	0.5	50	4						13
MPS6530	TO-92 (92)	60	40	5	50	40	25	500	500	10	0.5	100	5						13
							40	120	100	1									
							30	10	1										
MPS6531	TO-92 (92)	60	40	5	50	40	50	500	500	10	0.3	100	5						13
							90	270	100	1									
							60	10	1										
MPS6532	TO-92 (92)	50	30	5	100	30	30	100	100	1	0.5	100	5						13
NCBT13	TO-92 (92)	80	40	4	100	30	40	20	1	0.15		100	6	150	20				13
PN3566	TO-92 (92)	40	30	5	50	20	80	600	10	10	1	100	25	40	700	30			13
PN3567	TO-92 (92)	80	40	5	50	40	40	120	30	1	0.25	150	20	60	900	50			13
PN3569	TO-92 (92)	80	40	5	50	40	100	300	150	1	0.25	150		60	900	50			13
PN5449	TO-92 (92)	50	30	5	100	20	100	300	50	2	0.6	100		100	50				13
PN5816	TO-92 (92)	50	40	5	100	25	100	200	2	2	0.75	500		100	50				13
2N5550	TO-92 (92)	160	140	6	100	100	20	50	5	5	0.15	10	6	100	300	10	10	8	16
2N5551	TO-92 (92)	180	160	6	50	120	30	50	5	5	0.25	50	6	100	300	10	8	8	16
2N5830	TO-92 (92)	120	100	5	50	100	60	500	10	5	0.2	50		100	500	10			16

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TEST CONDITIONS:

(1) IC = 300 μ A, VCE = 10V, f = 1 kHz. (2) IC = 150 mA, VCC = 30V, IB¹ = IB² = 15 mA. (3) IC = 100 μ A, VCE = 10V, f = 1 kHz. (4) IC = 300 mA, VCC = 25V, IB¹ = IB² = 30 mA. (5) IC = 100 μ A, VCE = 4.5V, f = 15.7 kHz. (6) IC = 10 mA, VCC = 3V, IB¹ = IB² = 1 mA. (7) IC = 100 μ A, VCE = 5V, f = 15.7 kHz. (8) IC = 250 μ A, VCE = 5V, f = 10 Hz-15.7 kHz. (9) IC = 3 mA, VCE = 10V, f = 1 MHz. (10) IC = 10 μ A, VCE = 5V, f = 15.7 kHz.

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PNP Transistors



GENERAL PURPOSE AMPS AND SWITCHES (Continued)

Type No.	Case Style	V _{CE0} (V) Min	V _{CE0} (V) Max	V _{BE0} (V) Min	V _{BE0} (V) Max	I _{CB0} (mA) @ V _{CE0} (V)	h _{FE} @ I _C (mA) & V _{CE} (V)	V _{CE(SAT)} (V) Max	V _{BE(SAT)} (V) Min	I _C (mA) @ V _{CE(SAT)} (V) Max	C _{ob} (pF) Max	f _T (MHz) Min	f _T (MHz) Max	I _C (mA) @ f _T (MHz) Max	t _{off} (ns) Max	NF (dB) Max	Test Conditions	Process No.
MPSL01	TO-92 (92)	140	120	6	1 μ A	40	50 300 10	0.2	1.2	10	8	60		10				16
MP8098	TO-92 (92)	60	0	6	100	60	100 300 1 100 10 5 75 100 5	0.3	1.4	50	6	150		10				18
MP8099	TO-92 (92)	80	80	6	100	60	100 300 1 100 10 5 75 100 5	0.3		100	6	150		10				18
TIS98	TO-92 (97)		60		10	40	100 300 1	0.5		100		2		10				18
TIS99	TO-92 (97)		65		10	40	55 300 100	0.5		100		2		10				18
2N696	TO-5	60		5	1 μ A	30	20 60 150 10	1.5	1.3	150	20	40		50				19
2N697	TO-5	60	45	5	1 μ A	30	40 120 150 10	1.5	1.3	150	35	50		50				19
2N718	TO-18	60	30	5	1 μ A	30	40 120 150 10	1.5	1.3	150	35	50		15				19
2N718A	TO-18	75		7	10	60	20 500 10 40 150 10 35 10 10 20 100 μ A	1.5	1.3	150	25	60		50		12	1	19
2N956	TO-18	75	35	7	10	60	40 500 10 100 300 150 10 75 10 10 35 100 μ A 20 10 μ A	1.5	1.3	150	25	70		50		8	1	19
2N1420	TO-5	60	30	5	1 μ A	30	100 300 150 10	1.5	1.3	150	35	50		50				19
2N1566	TO-5	80	60	5	1 μ A	40	80 200 5 (1 kHz)	1.0		10	10	60		5				19
2N2218	TO-5	60	30	5	10	50	20 500 10 20 150 1 40 120 150 10 35 10 10 25 1 10 20 100 μ A	0.4	1.3	150	8	250		20				19
2N2218A	TO-5	75	40	6	10	60	25 500 10 20 150 1 40 120 150 10 35 10 10 25 1 10 20 100 μ A	0.3	0.6	1.2	8	250		20			2	19

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GENERAL PURPOSE AMPS AND SWITCHES (Continued)

Type No.	Case Style	V _{CEO} (V) Min	V _{CEO} (V) Min	V _{BE} (V) Min	V _{CE} (V) Max	I _{CBO} (nA) @ V _{CB} (V) Max	h _{FE} @ I _C (mA) & V _{CE} (V) Min Max	V _{CE(SAT)} (V) Max	V _{BE(SAT)} (V) Min Max	I _C (mA) Min Max	C _{ob} (pF) Max	f _T (MHz) Min Max	t _{off} (ns) Max	NF (dB) Max	Test Conditions	Process No.	
2N2219	TO-5	60	30	5	10	50	30 50 100 300 500 1000	0.4	1.3	150 500	8	250	20			19	
2N2219A	TO-5	75	40	6	10	60	40 50 100 300 500 1000	0.6	1.2	150 500	8	300	20	285	2	19	
2N2221	TO-18	60	30	5	10	50	20 30 40 50 60 70 80 90 100 110 120 130 140 150 160 170 180 190 200 210 220 230 240 250 260 270 280 290 300 310 320 330 340 350 360 370 380 390 400 410 420 430 440 450 460 470 480 490 500 510 520 530 540 550 560 570 580 590 600 610 620 630 640 650 660 670 680 690 700 710 720 730 740 750 760 770 780 790 800 810 820 830 840 850 860 870 880 890 900 910 920 930 940 950 960 970 980 990 1000	0.4	1.3	150 500	8	250	20			19	
2N2221A	TO-18	75	40	6	10	60	20 30 40 50 60 70 80 90 100 110 120 130 140 150 160 170 180 190 200 210 220 230 240 250 260 270 280 290 300 310 320 330 340 350 360 370 380 390 400 410 420 430 440 450 460 470 480 490 500 510 520 530 540 550 560 570 580 590 600 610 620 630 640 650 660 670 680 690 700 710 720 730 740 750 760 770 780 790 800 810 820 830 840 850 860 870 880 890 900 910 920 930 940 950 960 970 980 990 1000	0.6	1.2	150 500	8	250	20		2	19	
2N2222	TO-18	60	30	5	10	50	30 50 100 300 500 1000	0.4	1.3	150 500	8	250	20			19	
2N2222A	TO-18	75	40	6	10	60	40 50 100 300 500 1000	0.6	1.2	150 500	8	250	20	285	4	2/3	19
2N2397	TO-18	60		7	50	60	35 50 100 200 500 1000	1	1.3	150 500	15					19	

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TEST CONDITIONS:

I_C = 300 μ A, V_{CE} = 10V, f = 1 kHz. (2) I_C = 150 mA, V_{CE} = 30V, I_B¹ = I_B² = 15 mA. (3) I_C = 100 μ A, V_{CE} = 10V, f = 1 kHz. (4) I_C = 300 mA, V_{CE} = 25V, I_B¹ = I_B² = 30 mA. (5) I_C = 100 μ A, V_{CE} = 4.5V, f = 15.7 kHz. (6) I_C = 10 mA, V_{CE} = 3V, I_B¹ = I_B² = 1 mA. (7) I_C = 100 μ A, V_{CE} = 5V, f = 15.7 kHz. (8) I_C = 250 μ A, V_{CE} = 5V, f = 10 Hz-15.7 kHz. (9) I_C = 3 mA, V_{CE} = 10V, f = 1 MHz. (10) I_C = 10 μ A, V_{CE} = 5V, f = 15.7 kHz.

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GENERAL PURPOSE AMPS AND SWITCHES (Continued)

Type No.	Case Style	V _{CE} (V) Min	V _{CEO} (V) Min	V _{EB} (V) Min	I _{CBO} (nA) Max	V _{CB} (V)	I _{FE} @ Min Max	I _C & V _{CE} (mA) (V)	V _{CE} (SAT) (V) & V _{BE} (SAT) (V) Max Min	I _C @ (mA) Max	C _{ob} (pF) Max	f _T (MHz) Min Max	I _C @ (mA) Max	t _{off} (ns) Max	NF (dB) Max	Test Conditions	Process No.
2N3115	TO-18	60	20	5	25	50	40 120 150	10	0.5	1.3 150	8	250	20	500		2	19
2N3116	TO-18	60	20	5	25	50	100 300 150	10	0.5	1.3 150	8	250	20	500		2	19
2N3299	TO-5	60	30	5	10*	50	20 500 150	10	0.22	1.1 150	8	250	50	150		4	19
							40 120 150	10	0.6	1.5 500							
							35 10 10	10									
							25 1 10	10									
2N3300	TO-5	60	30	5	10*	50	20 500 150	10	0.22	1.1 150	8	250	50	150		4	19
							50 300 150	10	0.6	1.5 500							
							75 10 10	10									
							50 1 10	10									
2N3301	TO-18	60	30	5	10*	50	35 500 150	10	0.22	1.1 150	8	250	50	150		4	19
							20 150 1	1	0.6	1.5 500							
							40 120 150	10									
							35 10 10	10									
							25 1 10	10									
2N3302	TO-18	60	30	5	10*	50	20 500 150	10	0.22	1.1 150	8	250	50	150		4	19
							50 300 150	10	0.6	1.5 500							
							75 10 10	10									
							50 1 10	10									
2N3414	TO-92 (94)	25	25	5	100	25	75 225 2	4.5	0.3	0.5 1.3 50							19
2N3641	TO-92 (92)	Same as PN3641, see page 1-22 for explanation															
2N3642	TO-92 (92)	Same as PN3642, see page 1-22 for explanation															
2N3643	TO-92 (92)	Same as PN3643, see page 1-22 for explanation															
2N3678	TO-5	75	55	6	10	60	25 500 150	10	0.4	0.6 1.2 150				250		2	19
							20 150 1	1	1.0	2.0 500							
							40 150 10	10									
							35 10 10	10									
							25 1 10	10									
2N4140	TO-92 (92)	Same as PN4140, see page 1-22 for explanation															



GENERAL PURPOSE AMPS AND SWITCHES (Continued)

Type No.	Case Style	V _{CEO} (V)	V _{CE0} (V)	V _{BE0} (V)	I _{CBO} (nA) @ V _{CB} (V)	I _{FE} Min	I _C @ V _{CE} (mA)	V _{CE(SAT)} (V) & V _{BE(SAT)} (V)	I _C (mA)	C _{ob} (pF)	f _T (MHz)	I _C (mA)	t _{off} (ns)	NF (dB)	Test Conditions	Process No.
2N4141	TO-92 (92)	Same as PN4141, see page 1-22 for explanation	Same as PN4141, see page 1-22 for explanation	Same as PN4141, see page 1-22 for explanation	Same as PN4141, see page 1-22 for explanation	Same as PN4141, see page 1-22 for explanation	Same as PN4141, see page 1-22 for explanation	Same as PN4141, see page 1-22 for explanation	Same as PN4141, see page 1-22 for explanation	Same as PN4141, see page 1-22 for explanation	Same as PN4141, see page 1-22 for explanation	Same as PN4141, see page 1-22 for explanation	Same as PN4141, see page 1-22 for explanation	Same as PN4141, see page 1-22 for explanation	Same as PN4141, see page 1-22 for explanation	19
2N4969	TO-92 (92)	Same as PN2221, see below for explanation	Same as PN2221, see below for explanation	Same as PN2221, see below for explanation	Same as PN2221, see below for explanation	Same as PN2221, see below for explanation	Same as PN2221, see below for explanation	Same as PN2221, see below for explanation	Same as PN2221, see below for explanation	Same as PN2221, see below for explanation	Same as PN2221, see below for explanation	Same as PN2221, see below for explanation	Same as PN2221, see below for explanation	Same as PN2221, see below for explanation	Same as PN2221, see below for explanation	19
2N4970	TO-92 (92)	50	30	5		100	350	150	10	8	200	20				19
2N5128	TO-92 (92)	Same as PN5128, see page 1-22 for explanation	Same as PN5128, see page 1-22 for explanation	Same as PN5128, see page 1-22 for explanation	Same as PN5128, see page 1-22 for explanation	Same as PN5128, see page 1-22 for explanation	Same as PN5128, see page 1-22 for explanation	Same as PN5128, see page 1-22 for explanation	Same as PN5128, see page 1-22 for explanation	Same as PN5128, see page 1-22 for explanation	Same as PN5128, see page 1-22 for explanation	Same as PN5128, see page 1-22 for explanation	Same as PN5128, see page 1-22 for explanation	Same as PN5128, see page 1-22 for explanation	Same as PN5128, see page 1-22 for explanation	19
2N5129	TO-92 (92)	Same as PN5129, see page 1-22 for explanation	Same as PN5129, see page 1-22 for explanation	Same as PN5129, see page 1-22 for explanation	Same as PN5129, see page 1-22 for explanation	Same as PN5129, see page 1-22 for explanation	Same as PN5129, see page 1-22 for explanation	Same as PN5129, see page 1-22 for explanation	Same as PN5129, see page 1-22 for explanation	Same as PN5129, see page 1-22 for explanation	Same as PN5129, see page 1-22 for explanation	Same as PN5129, see page 1-22 for explanation	Same as PN5129, see page 1-22 for explanation	Same as PN5129, see page 1-22 for explanation	Same as PN5129, see page 1-22 for explanation	19
2N5135	TO-92 (92)	Same as PN5135, see page 1-22 for explanation	Same as PN5135, see page 1-22 for explanation	Same as PN5135, see page 1-22 for explanation	Same as PN5135, see page 1-22 for explanation	Same as PN5135, see page 1-22 for explanation	Same as PN5135, see page 1-22 for explanation	Same as PN5135, see page 1-22 for explanation	Same as PN5135, see page 1-22 for explanation	Same as PN5135, see page 1-22 for explanation	Same as PN5135, see page 1-22 for explanation	Same as PN5135, see page 1-22 for explanation	Same as PN5135, see page 1-22 for explanation	Same as PN5135, see page 1-22 for explanation	Same as PN5135, see page 1-22 for explanation	19
2N5136	TO-92 (92)	Same as PN5136, see page 1-22 for explanation	Same as PN5136, see page 1-22 for explanation	Same as PN5136, see page 1-22 for explanation	Same as PN5136, see page 1-22 for explanation	Same as PN5136, see page 1-22 for explanation	Same as PN5136, see page 1-22 for explanation	Same as PN5136, see page 1-22 for explanation	Same as PN5136, see page 1-22 for explanation	Same as PN5136, see page 1-22 for explanation	Same as PN5136, see page 1-22 for explanation	Same as PN5136, see page 1-22 for explanation	Same as PN5136, see page 1-22 for explanation	Same as PN5136, see page 1-22 for explanation	Same as PN5136, see page 1-22 for explanation	19
2N5137	TO-92 (92)	Same as PN5137, see page 1-22 for explanation	Same as PN5137, see page 1-22 for explanation	Same as PN5137, see page 1-22 for explanation	Same as PN5137, see page 1-22 for explanation	Same as PN5137, see page 1-22 for explanation	Same as PN5137, see page 1-22 for explanation	Same as PN5137, see page 1-22 for explanation	Same as PN5137, see page 1-22 for explanation	Same as PN5137, see page 1-22 for explanation	Same as PN5137, see page 1-22 for explanation	Same as PN5137, see page 1-22 for explanation	Same as PN5137, see page 1-22 for explanation	Same as PN5137, see page 1-22 for explanation	Same as PN5137, see page 1-22 for explanation	19
PN2221	TO-92 (92)	60	30	5	10	20	500	10	0.4	1.3	150	8	250	20		19
PN2221A	TO-92 (92)	75	40	6	10	25	500	10	0.3	0.6	1.2	150	8	250	20	2
PN2222	TO-92 (92)	60	30	5	10	30	500	10	0.4	1.3	150	8	250	20		19

TEST CONDITIONS:

(1) I_C = 300 μ A, V_{CE} = 10V, f = 1 kHz. (2) I_C = 150 μ A, V_{CE} = 30V, I_B¹ = I_B² = 15 mA. (3) I_C = 100 μ A, V_{CE} = 10V, f = 1 kHz. (4) I_C = 300 mA, V_{CE} = 25V, I_B¹ = I_B² = 30 mA. (5) I_C = 100 μ A, V_{CE} = 4.5V, f = 15.7 kHz. (6) I_C = 10 mA, V_{CE} = 3V, I_B¹ = I_B² = 1 mA. (7) I_C = 100 μ A, V_{CE} = 5V, f = 15.7 kHz. (8) I_C = 250 μ A, V_{CE} = 5V, f = 10 Hz-15.7 kHz. (9) I_C = 3 mA, V_{CE} = 10V, f = 1 MHz. (10) I_C = 10 μ A, V_{CE} = 5V, f = 15.7 kHz.

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GENERAL PURPOSE AMPS AND SWITCHES (Continued)

Type No.	Case Style	V _{CE0} (V) Min	V _{BE0} (V) Min	I _{CB0} (nA) @ V _{CB} (V) Max	h _{FE} Min Max	I _C @ V _{CE} & V _{BE(SAT)} (V) (V) Max Min	V _{CE(SAT)} (V) Max	V _{BE(SAT)} (V) Min	I _C (mA) @ V _{CE(SAT)} (V) Min Max	C _{ob} (pF) Max	f _T (MHz) Min Max	I _C (mA) @ V _{CE(SAT)} (V) Min Max	t _{off} (ns) Max	NF (dB) Max	Test Conditions	Process No.
PN2222A	TO-92 (92)	40	6	10	40 50 100 300 75 35	500 150 10 1 1 100 μA	0.3 1.0 0.6 1.2	0.3 1.0 0.6 1.2	150 500 20	8	300	20	285		2	19
PN3641	TO-92 (92)	30	5	50*	15 40 120 150 15	500 10 10	0.22	0.22	150 50	8	250	50				19
PN3642	TO-92 (92)	45	5	50*	15 40 120 150 15	500 10 10	0.22	0.22	150 50	8	250	50				19
PN3643	TO-92 (92)	30	5	50*	20 100 300 75 35	500 10 10	0.22	0.22	150 50	8	250	50				19
PN4140	TO-92 (92)	30	5		20 100 300 75 35 25 20	500 10 10 100 μA	0.4 1.6	1.3 2.6	150 500 20	8	250	20	310		2	19
PN4141	TO-92 (92)	30	5		30 50 100 300 75 35 20	500 10 10 100 μA	0.4 1.6	1.3 2.6	150 500 20	8	250	20	310		2	19
PN5128	TO-92 (92)	12	3	50	35 20 35 350 20	50 10 10	0.25	0.25	150 50	10	200 800	50				19
PN5129	TO-92 (92)	12	3	50	35 20 35 350 20	50 10 10	0.25	0.25	150 50	10	200 800	50				19
PN5135	TO-92 (92)	25	4	300	50 15 50 60* 15	10 10 2	1.0	1.0	100 30	25	40 500	30				19
PN5136	TO-92 (92)	20	3	100	20 20 20 400 20	150 1 30	0.25	0.25	150 50	35	40 400	50				19
PN5137	TO-92 (92)	20	3	100	20 20 20 400 20	150 1 30	0.25	0.25	150 50	35	40 400	50				19
PN2218A	TO-237 (91)	40	6	10	25 20 40 120 35 25 20	500 1 150 10 10 100 μA	0.3 1.2	0.3 1.2	150 20	8	250	20	285		2	19

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GENERAL PURPOSE AMPS AND SWITCHES (Continued)

Type No.	Case Style	VCBO (V) Min	VCEO (V) Min	VEBO (V) Min	ICBO (mA) Max	hFE Min	hFE Max	IC (mA) Max	VCE (V) Max	VCE(SAT) (V) Max	VBE(SAT) (V) Min	IC (mA) Max	Cob (pF) Max	fT (MHz) Min	fT (MHz) Max	t _{off} (ns) Max	NF (dB) Max	Test Conditions	Process No.
TN2219	TO-237 (91)	60	30	5	10	30	500	10	10	0.4	1.3	150	8	50	20			19	
						50	150	1		1.6	2.6	500							
						100	300	10											
						75	10	10											
						50	1	10											
						35	0.1	10											
TN2219A	TO-237 (91)	75	40	6	10	40	500	10	10	0.3	0.6	1.2	8	60	20		4	3	19
						50	150	1		1.0	2.0	500							
						100	300	10											
						75	10	10											
						50	1	10											
						35	0.1	10											
TIS90	TO-92 (94)	40	40	5	100	100	300	50	2	0.25	0.6	1							19
TIS92	TO-92 (97)	40	40	5	100	100	300	50	2	0.25	0.6	1							19
2N915	TO-18	70	50	5	10	50	200	10	5	1.0	0.9	10	3.5	250	10				23
2N916	TO-18	45	25	5	10	50	200	10	1	0.5	0.9	10	6	300	10				23
2N3691	TO-92 (92)	Same as PN3691, see page 1-25 for explanation																	23
2N3692	TO-92 (92)	Same as PN3692, see page 1-25 for explanation																	23
2N3903	TO-92 (92)	60	40	6		15	100	1		0.2	0.6	0.85	4	250	10	225	6	6/7	23
						30	50	1		0.3	0.95	50							
						50	10	1											
						35	1	1											
						20	100 μ A	1											
2N3904	TO-92 (92)	60	40	6	30	30	100	1		0.2	0.65	0.85	4	300	10	250	5	6/7	23
						60	50	1		0.3	0.95	50							
						100	300	1											
						70	1	1											
						40	100 μ A	1											
2N3946	TO-18	60	40	6		20	50	1		0.2	0.6	0.9	4	250	10	375	5	6/7	23
						50	10	1		0.3	1.0	50							
						45	1	1											
						30	100 μ A	1											

TEST CONDITIONS:

(1) IC = 300 μ A, VCE = 10V, f = 1 kHz. (2) IC = 150 mA, VCC = 30V, IB¹ = IB² = 15 mA. (3) IC = 100 μ A, VCE = 10V, f = 1 kHz. (4) IC = 300 mA, VCC = 25V, IB¹ = IB² = 30 mA. (5) IC = 100 μ A, VCE = 4.5V, f = 15.7 kHz. (6) IC = 10 mA, VCC = 3V, IB¹ = IB² = 1 mA. (7) IC = 100 μ A, VCE = 5V, f = 15.7 kHz. (8) IC = 250 μ A, VCE = 5V, f = 10 Hz-15.7 kHz. (9) IC = 3 mA, VCE = 10V, f = 1 MHz. (10) IC = 10 μ A, VCE = 5V, f = 15.7 kHz.

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GENERAL PURPOSE AMPS AND SWITCHES (Continued)

Type No.	Case Style	VCBO (V) Min	VCEO (V) Min	VEBO (V) Min	ICBO (mA) Max	ICBO (mA) e	V _{CB} (V)	h _{FE} Min	h _{FE} e Max	IC (mA) e	V _{CE} (V) & V _{CE} (V)	V _{CE(SAT)} (V) Max	V _{BE(SAT)} (V) Min	IC (mA) e	C _{ob} (pF) Max	f _T (MHz) Min	f _T (MHz) Max	t _{off} (ns) Max	NF (dB) Max	Test Conditions	Process No.
2N3947	TO-18	60	40	6				40	50	10	1	0.2	0.5	0.9	4	300	10	450	5	6/7	23
								100	300	1	1	0.3	1.0	50							
								90	1	1	1										
								60	100	1	1										
2N4123	TO-92 (92)	40	30	5	50	50	20	25	50	50	1	0.3	0.95	50	4	250	10		6	7	23
								50	150	2	1										
2N4124	TO-92 (92)	30	25	5	50	50	20	60	50	50	1	0.3	0.95	50	4	300	10		5	7	23
								120	360	2	1										
MPS2711	TO-92 (92)	18	18	5	500	500	18	30	90	2	4.5				4						23
MPS2712	TO-92 (92)	18	18	5	500	500	18	75	225	2	4.5				4						23
MPS2716	TO-92 (92)	18	18	5	500	500	18	75	225	2	4.5				3.5						23
MPS2923	TO-92 (92)	25	25	5	500	500	25	90	180	2	10				12						23
								150	300	2	10				12						23
MPS2924	TO-92 (92)	25	25	5	500	500	25	150	300	2	10				12						23
MPS2925	TO-92 (92)	25	25	5	500	500	25	235	470	2	10				12						23
MPS2926	TO-92 (92)	25	25	5	500	500	18	35	470	2	10				3.5						23
MPS3642	TO-92 (92)	Same as PN3642, see page 1-22 for explanation																			23
MPS3721	TO-92 (92)				500	500	18	60	660	2	10				3.5						23
								40	160	10	10				3.5	200	800	10			23
MPS3826	TO-92 (92)	60	45	4	100	100	30	40	160	10	10				3.5	200	800	10			23
MPS3827	TO-92 (92)	60	45	4	100	100	30	100	400	10	10				3.5	200	800	10			23
MPS512	TO-92 (92)	40	30	4	50	50	30	30	100	100	10	0.5		50	3.5						23
								50	100	2	10				3.5						23
MPS513	TO-92 (92)	40	30	4	50	50	30	60	100	100	10	0.5		50	3.5						23
								90	180	2	10				3.5						23
MPS514	TO-92 (92)	40	25	4	50	50	30	90	100	100	10	0.5		50	3.5						23
								150	300	2	10				3.5						23
MPS515	TO-92 (92)	40	25	4	50	50	30	150	500	2	10	0.5		50	3.5						23

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GENERAL PURPOSE AMPS AND SWITCHES (Continued)

Type No.	Case Style	V _{CEO} (V) Min	V _{CE0} (V) Min	V _{EB0} (V) Min	I _{CBO} (nA) @ V _{CB} (V) Max	h _{FE} @ I _C (mA) & V _{CE} (V) Min Max	V _{CE(SAT)} (V) & V _{BE(SAT)} (V) Min Max	I _C (mA) @ V _{CE} (V) Min Max	C _{ob} (pF) Max	f _T (MHz) @ I _C (mA) Min Max	t _{off} (ns) Max	NF (dB) Max	Test Conditions	Process No.
NS3903	TO-18	60	40	6		15 30 50 35 20	0.2 0.3	100 50 150 1 100 μ A	4	250 10	225		6	23
NS3904	TO-18	60	40	6		30 60 100 70 40	0.2 0.3	100 50 300 1 100 μ A	4	300 10	250		6	23
PN3691	TO-92 (92)	35	20	4	50	40 160	0.7	10 1	3.5	200 500				23
PN3692	TO-92 (92)	35	20	4	50	100 400	0.7	10 1	3.5	200 500				23
ST3904	TO-92 (92)	60	40	6		40 70 100 60 30	0.2 0.3	0.1 1 10 50 100	4	300 10		8	7	23
2N2712	TO-92 (94)	18	18	5	500	75 225		2 4.5	12	80 300				27
2N2714	TO-92 (94)	18	18	5	500	75 225	0.3	2 4.5						27
2N3394	TO-92 (94)	25	25	5	100	55 110		2 4.5	10					27
2N3693	TO-92 (92)	Same as MPS3693, see page 1-26 for explanation												
2N3694	TO-92 (92)	Same as PN3694, see page 1-26 for explanation												
2N3721	TO-92 (94)	18	18	5	500	60 660 (1 kHz)		2 10	12					27
2N3827	TO-92 (94)	60	45	4	100	30 400		10	3.5	200 800				27
2N3858	TO-92 (94)	30	30	4	500	60 120		2 4.5	4	90 250				27

TEST CONDITIONS:

(1) I_C = 300 μ A, V_{CE} = 10V, f = 1 kHz. (2) I_C = 150 mA, V_{CE} = 30V, I_B¹ = I_B² = 15 mA. (3) I_C = 100 μ A, V_{CE} = 10V, f = 1 kHz. (4) I_C = 300 mA, V_{CC} = 25V, I_B¹ = I_B² = 30 mA. (5) I_C = 100 μ A, V_{CE} = 4.5V, f = 15.7 kHz. (6) I_C = 10 mA, V_{CC} = 3V, I_B¹ = I_B² = 1 mA. (7) I_C = 100 μ A, V_{CE} = 5V, f = 15.7 kHz. (8) I_C = 250 μ A, V_{CE} = 5V, f = 10 Hz-15.7 kHz. (9) I_C = 3 mA, V_{CE} = 10V, f = 1 MHz. (10) I_C = 10 μ A, V_{CE} = 5V, f = 15.7 kHz.

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GENERAL PURPOSE AMPS AND SWITCHES (Continued)

Type No.	Case Style	V _{CE0} (V) Min	V _{CE0} (V) Max	V _{BE0} (V) Min	V _{BE0} (V) Max	I _{CB0} (mA) Max	V _{CB} (V) Max	h _{FE} Min	h _{FE} Max	I _C (mA) Max	V _{CE} (V) Max	V _{CE(SAT)} (V) Max	V _{BE(SAT)} (V) Min	I _C (mA) Max	C _{ob} (pF) Max	f _T (MHz) Min	f _T (MHz) Max	I _C (mA) Max	t _{off} (ns) Max	NF (dB) Max	Test Conditions	Process No.
2N3859	TO-92 (94)	30	30	4	4	500	18	100	200	2	4.5				4	90	250	2				27
2N3860	TO-92 (94)	30	30	4	4	500	18	150	300	2	4.5				4	90	250	2				27
2N5127	TO-92 (92)	Same as PN5127, see below for explanation																				27
2N5131	TO-92 (92)	Same as PN5131, see below for explanation																				27
2N5132	TO-92 (92)	Same as PN5132, see below for explanation																				27
2N5219	TO-92 (92)	20	15	3	3	100	10	35	500	2	10	0.4	1.0	10	4	150	10					27
2N5223	TO-92 (92)	25	20	3	3	100	10	50	800	2	10	0.7	1.2	10	4	150	10					27
MPS3693	TO-92 (92)	45	45	4	4	50	35	40	160	10	10				3.5	200	10	4	9			27
MPS3694	TO-92 (92)	45	45	4	4	50	35	100	400	10	10				3.5	200	10	4	9			27
MPS6564	TO-92 (92)		45	5	5	500	40	25	10	5		0.5		10	4							27
MPS6565	TO-92 (92)	60	45	4	4	100	30	40	160	10	10	0.4		10	3.5							27
MPS6566	TO-92 (92)	60	45	4	4	100	30	100	400	10	10	0.4		10	3.5	200	10					27
MPSA10	TO-92 (92)		40	4	4	100	30	40	400	5	10				4	50	5					27
PN3694	TO-92 (92)	45	45	4	4	50	30	100	400	10	1				6	200	10					27
PN5127	TO-92 (92)	20	12	3	3	50	10	15	300	2	10	0.3	1.0	10	3.5	150	2					27
PN5131	TO-92 (92)	20	15	3	3	50	10	35	500	10	1	1.0		10	6	100	10					27
PN5132	TO-92 (92)	20	20	3	3	50	10	30	400	10	10	2.0	0.9	10	3.5	200	10					27

TEST CONDITIONS:

(1) I_C = 300 μA, V_{CE} = 10V, f = 1 kHz. (2) I_C = 150 mA, V_{CE} = 30V, I_B¹ = I_B² = 15 mA. (3) I_C = 100 μA, V_{CE} = 10V, f = 1 kHz. (4) I_C = 300 mA, V_{CE} = 25V, I_B¹ = I_B² = 30 mA. (5) I_C = 100 μA, V_{CE} = 4.5V, f = 15.7 kHz. (6) I_C = 10 mA, V_{CE} = 3V, I_B¹ = I_B² = 1 mA. (7) I_C = 100 μA, V_{CE} = 5V, f = 15.7 kHz. (8) I_C = 250 μA, V_{CE} = 5V, f = 10 Hz-15.7 kHz. (9) I_C = 3 mA, V_{CE} = 10V, f = 1 MHz. (10) I_C = 10 μA, V_{CE} = 5V, f = 15.7 kHz.

T-29-01